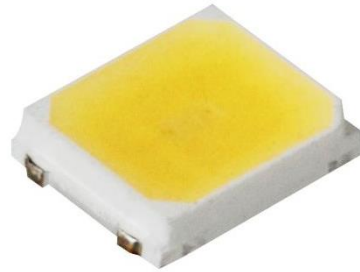


Mid-Power LED - 3528 Series

STW8A12D – 0.5W (Cool, Neutral, Warm)



Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension. Package Size: 3.5x2.8x0.7mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

Features and Benefits

- Market Standard 3528 Package Size
- High Color Quality, CRI Min. 80
- RoHS compliant

Key Applications

- Interior lighting
- General lighting
- Indoor and outdoor displays
- Architectural / Decorative lighting

Table 1. Product Selection Table

Part Number	CCT			
	Color	Min.	Typ.	Max.
STW8A12D	Cool White	4700K	5600K	7000K
STW8A12D	Neutral White	3700K	4200K	4700K
STW8A12D	Warm White	2600K	3000K	3700K

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Performance Characteristics

Table 2. Product Selection Guide, I_F = 150mA, T_j = 25°C, RH30%

Part Number	CCT (K) ^[1]	RANK	Luminous Intensity ^[2]		Luminous Flux ^[3]		CRI
	Typ.		I _v (cd)		Φ _v (lm)		R _a
			Min	Max	Min	Max	Min.
STW8A12D	6500	J16	16	18	49.6	55.8	80
		J18	18	20	55.8	62.0	80
		K20	20	22	62.0	68.2	80
	5600	J16	16	18	49.6	55.8	80
		J18	18	20	55.8	62.0	80
		K20	20	22	62.0	68.2	80
	5000	J18	18	20	55.8	62.0	80
		K20	20	22	62.0	68.2	80
		K22	22	24	68.2	74.4	80
	4500	J18	18	20	54.9	61.0	80
		K20	20	22	61.0	67.1	80
		K22	22	24	68.2	74.4	80
	4000	J18	18	20	54.9	61.0	80
		K20	20	22	61.0	67.1	80
		K22	22	24	68.2	74.4	80
	3500	J16	16	18	48.0	54.0	80
		J18	18	20	54.0	60.0	80
		K20	20	22	60.0	66.0	80
	3000	J16	16	18	48.0	54.0	80
		J18	18	20	54.0	60.0	80
	2700	J16	16	18	48.0	54.0	80
		J18	18	20	54.0	60.0	80
	2450	J16	16.0	18.0	48.0	54.0	80
		J18	18.0	20.0	54.0	60.0	80
	2200	J16	16.0	18.0	48.0	54.0	80
		J18	18.0	20.0	54.0	60.0	80

Notes :

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

(2) Seoul Semiconductor maintains a tolerance of ±5% on Intensity and power measurements.

The luminous intensity I_v was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.

(3) The lumen table is only for reference.

Performance Characteristics

Table 3. Characteristics, $I_F=150\text{mA}$, $T_J= 25^\circ\text{C}$, RH30%

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Forward Current	I_F	-	150	180	mA
Forward Voltage	V_F	-	3.2	3.5	V
Luminous Intensity ^[1] (2,700K) ^[2]	I_v	-	18.2	-	cd
CRI ^[3]	R_a	80	83	90	
Viewing Angle	$2\theta_{1/2}$	-	120	-	Deg.
Storage Temperature	T_{stg}	-40	-	85	$^\circ\text{C}$
Thermal resistance (J to S) ^[4]	$R\theta_{J-S}$	-	35	-	$^\circ\text{C/W}$
ESD Sensitivity(HBM)	-	Class 2 JESD22-A114-E			

Table 4. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_F	180	mA
Power Dissipation	P_D	0.63	W
Junction Temperature	T_j	125	$^\circ\text{C}$
Operating Temperature	T_{opr}	-40 ~ + 85	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 ~ + 100	$^\circ\text{C}$

Notes :

- (1) Seoul Semiconductor maintains a tolerance of $\pm 5\%$ on Intensity and power measurements.
- (2) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.
- (3) Tolerance is ± 2.0 on CRI, $\pm 0.1\text{V}$ on VF measurements.
- (4) Thermal resistance is junction to Solder.
- (5) I_{FP} conditions with pulse width $\leq 10\text{ms}$ and duty cycle $\leq 10\%$
- (6) The products are sensitive to static electricity and must be carefully taken when handling products
- (7) It is recommended to use it in the condition that the reliability is secured within the Max value.
 - **Calculated performance values are for reference only.**
 - **All measurements were made under the standardized environment of Seoul Semiconductor.**

Characteristics Graph

Fig 1. Color Spectrum, $T_j = 25^\circ\text{C}$, $I_F = 150\text{mA}$

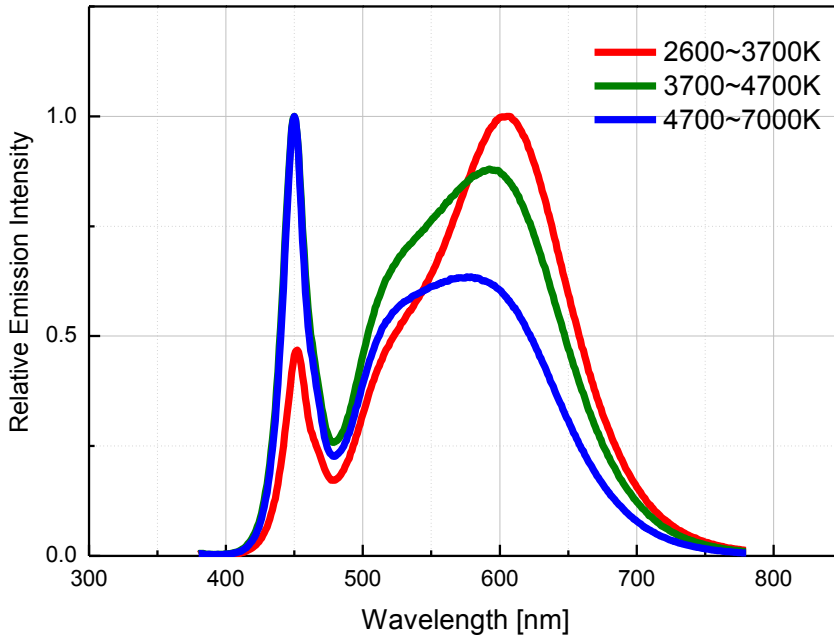
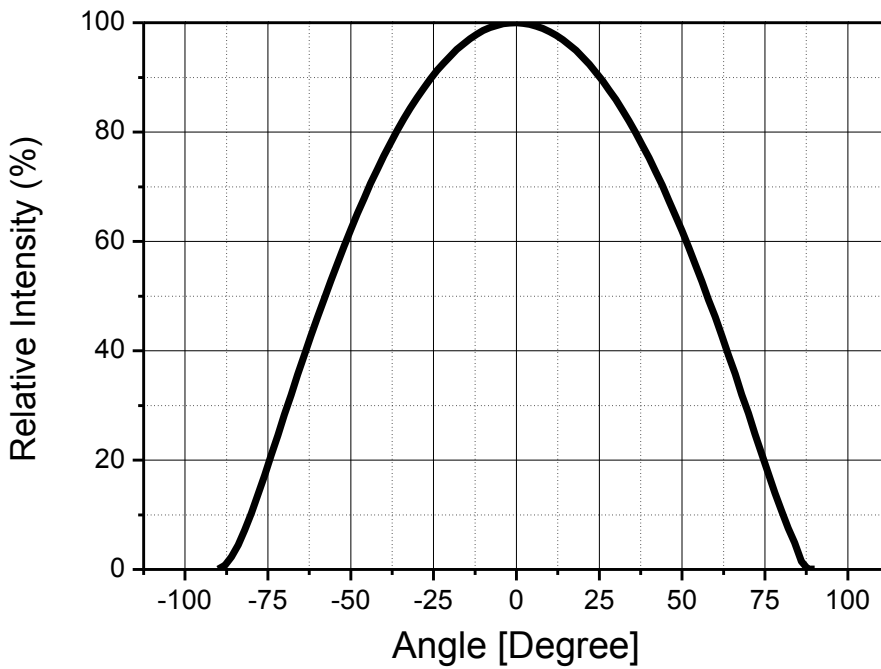


Fig 2. Radiant Pattern, $T_j = 25^\circ\text{C}$, $I_F = 150\text{mA}$



Characteristics Graph

Fig 3. Forward Voltage vs. Forward Current, $T_j = 25^\circ\text{C}$

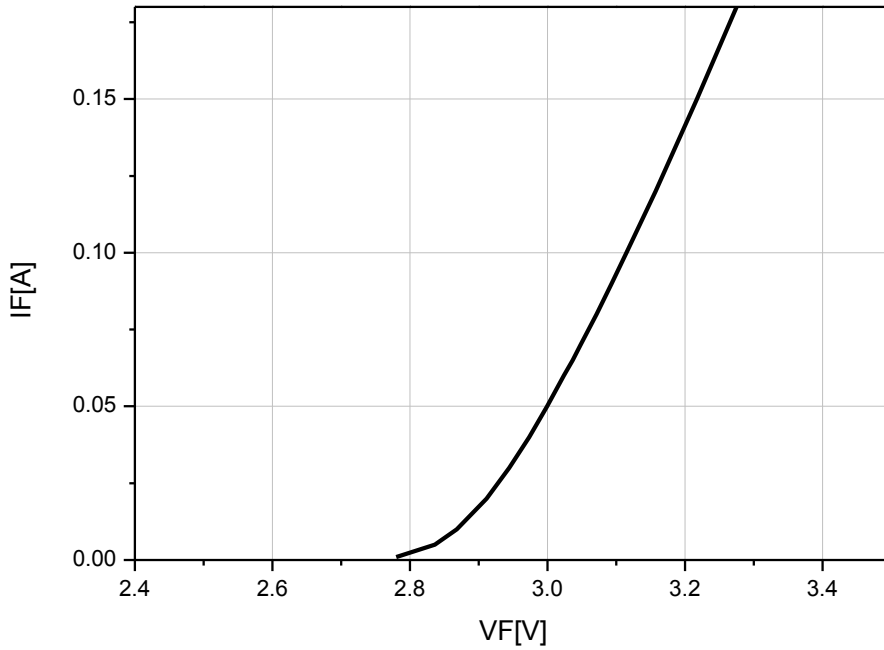
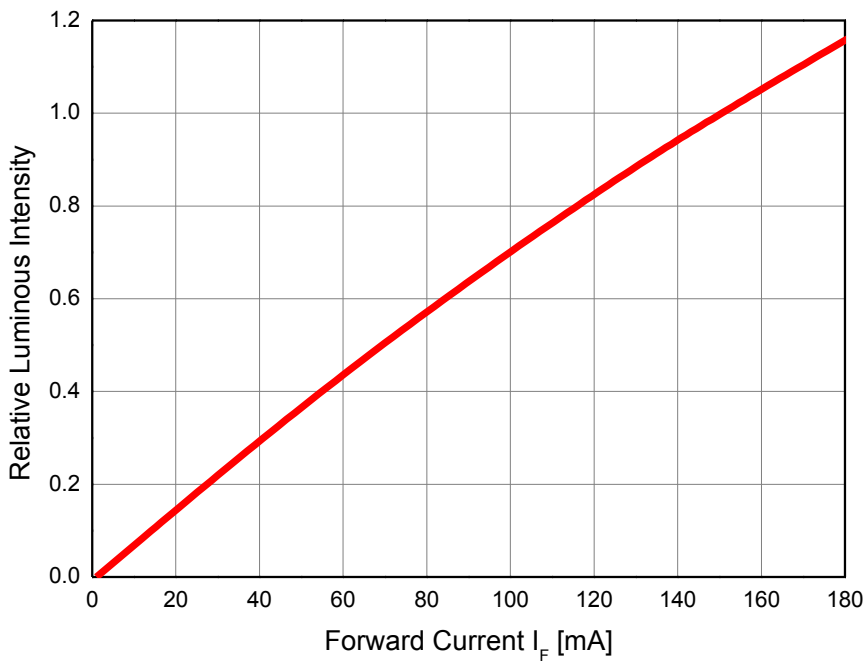
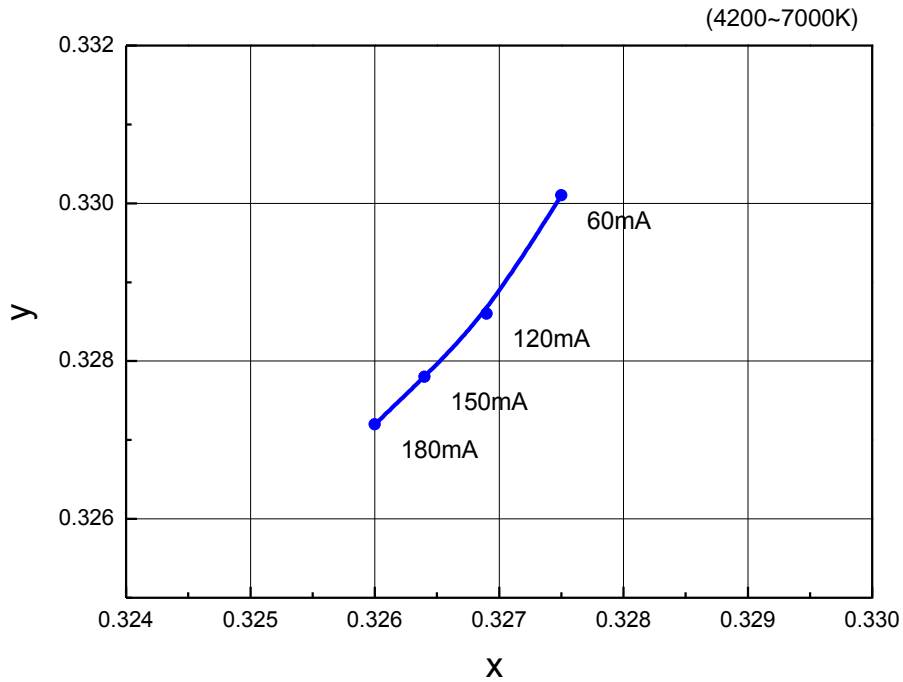
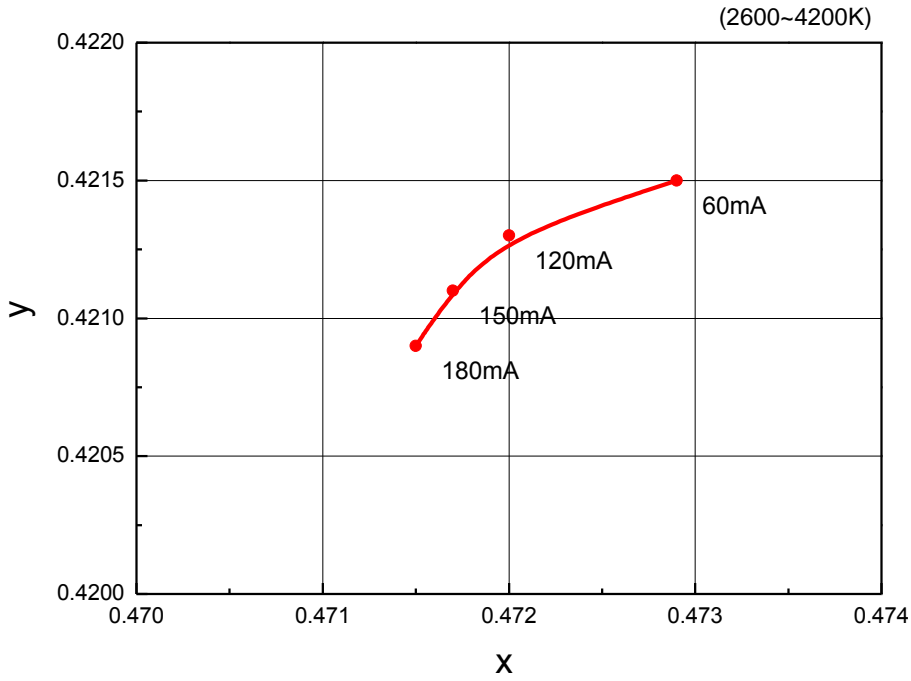


Fig 4. Forward Current vs. Relative Luminous Intensity, $T_j = 25^\circ\text{C}$



Characteristics Graph

Fig 5. Forward Current vs. CIE X,Y Shift, $T_j = 25^\circ\text{C}$



Characteristics Graph

Fig 6. Junction Temperature vs. Relative Luminous Intensity, $I_F=150\text{mA}$

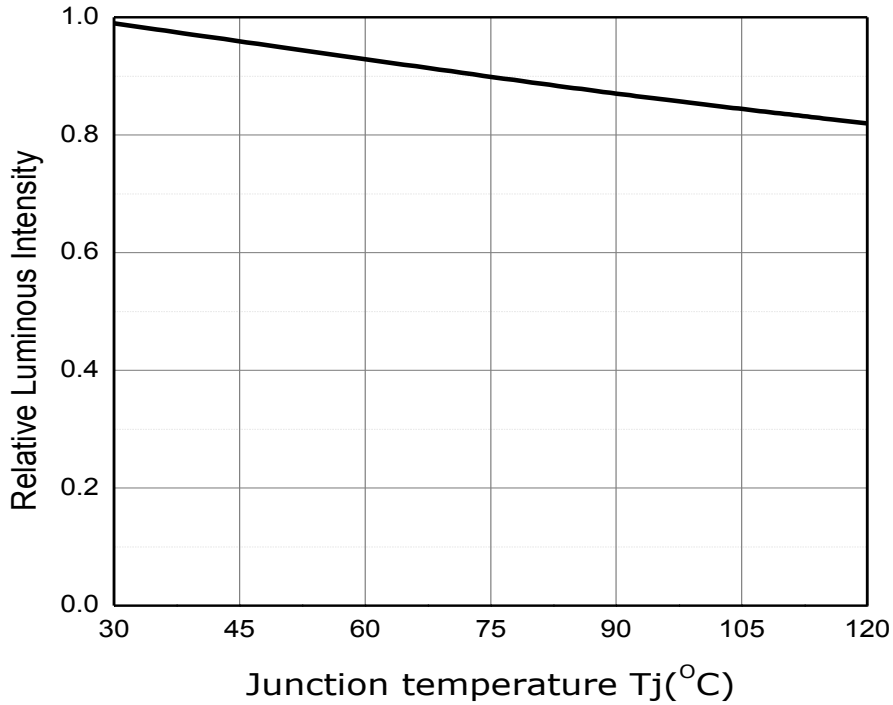
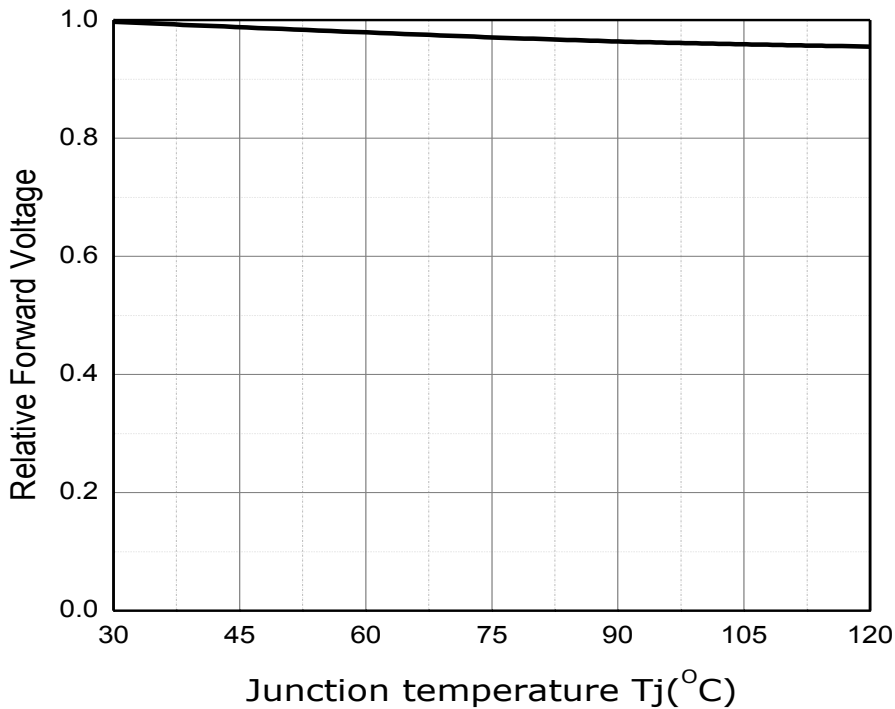
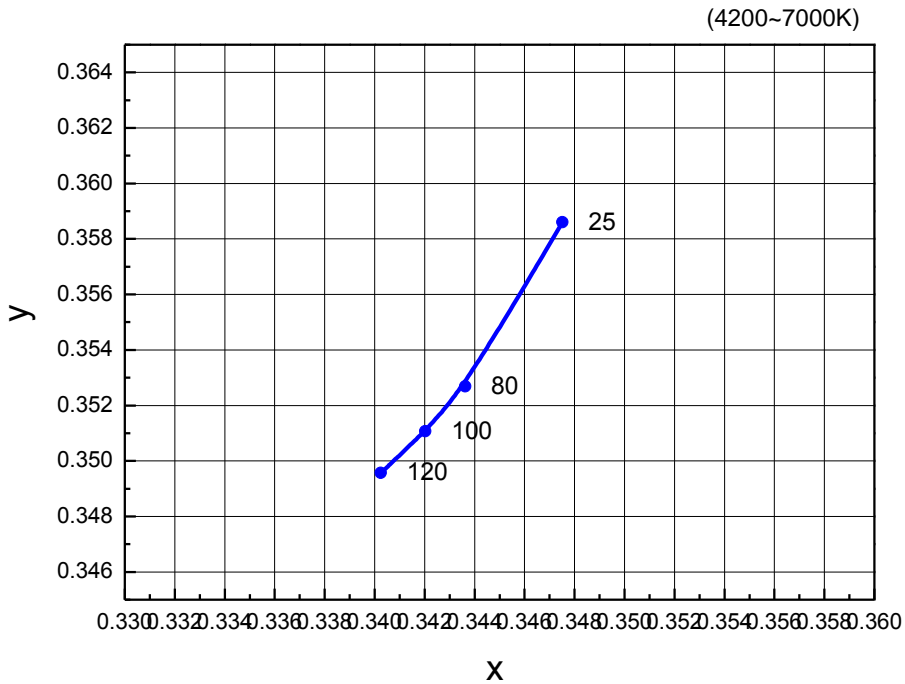
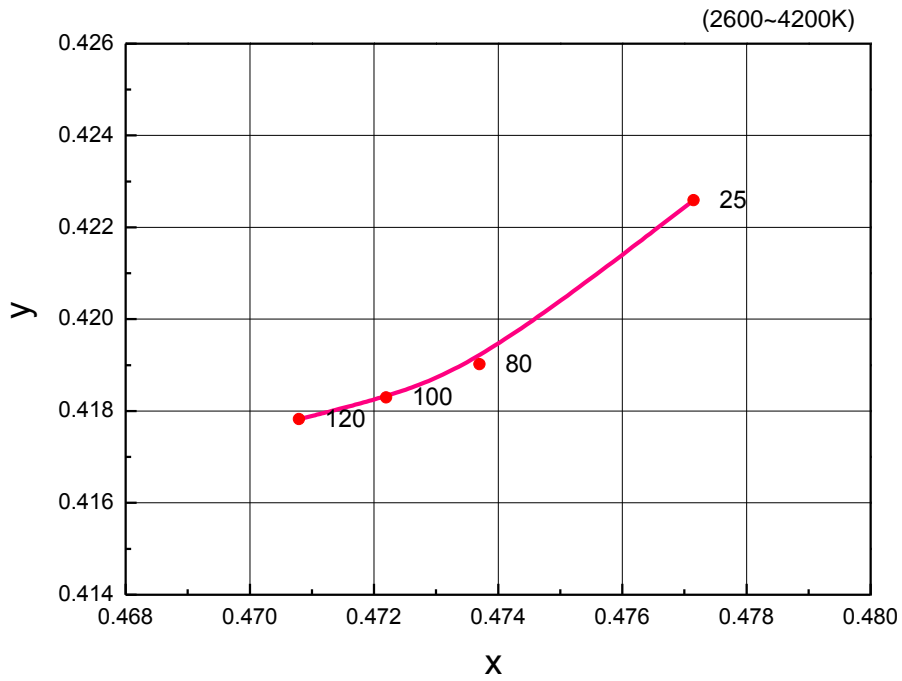


Fig 7. Junction Temperature vs. Relative Forward Voltage, $I_F=150\text{mA}$

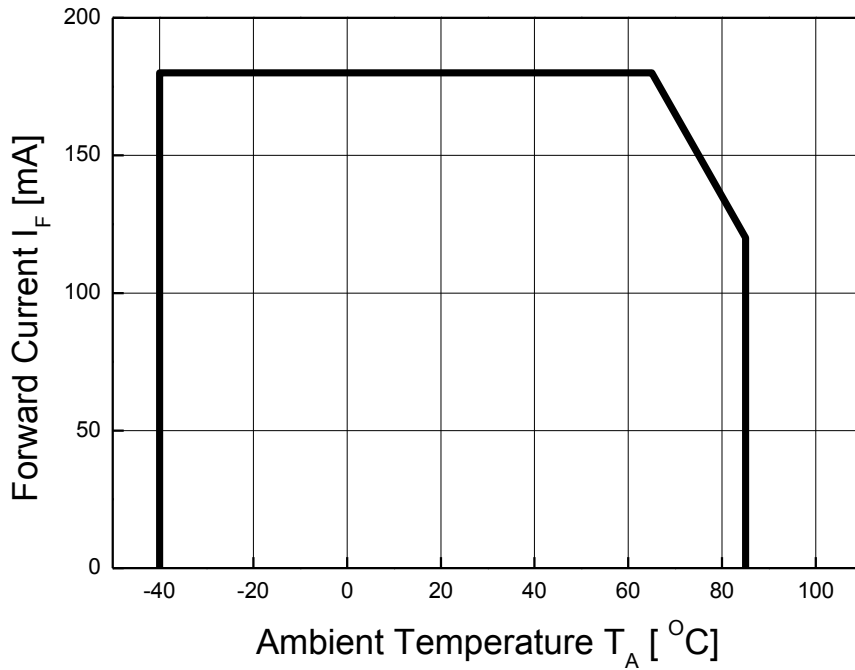


Characteristics Graph

Fig 8. Chromaticity Coordinate vs. Junction Temperature, $I_F=150\text{mA}$


Characteristics Graph

Fig 9. Ambient Temperature vs. Maximum Forward Current, $T_{j_max} = 125^{\circ}\text{C}$



Color Bin Structure

Table 5. Bin Code description, $T_j=25^{\circ}\text{C}$, $I_F=150\text{mA}$

Part Number	Luminous Intensity (cd)			Color Chromaticity Coordinate	Typical Forward Voltage (V)		
	Bin Code	Min.	Max.		Bin Code	Min.	Max.
STW8A12D	J16	16.0	18.0	Refer to Page. 12	Y3	2.9	3.0
	J18	18.0	20.0		Z1	3.0	3.1
	K20	20.0	22.0		Z2	3.1	3.2
	K22	22.0	24.0		Z3	3.2	3.3
					A1	3.3	3.4
					A2	3.4	3.5

Table 6. Intensity rank distribution

Available ranks

CCT	CIE	IV Rank			
6,000 ~ 7,000K	A	J16	J18	K20	K22
5,300 ~ 6,000K	B	J16	J18	K20	K22
4,700 ~ 5,300K	C	J16	J18	K20	K22
4,200 ~ 4,700K	D	J16	J18	K20	K22
3,700 ~ 4,200K	E	J16	J18	K20	K22
3,200 ~ 3,700K	F	J16	J18	K20	K22
2,900 ~ 3,200K	G	J16	J18	K20	K22
2,600 ~ 2,900K	H	J16	J18	K20	K22
2,300 ~ 2,600K	J	J16	J18	K20	K22
2,100 ~ 2,300K	K	J16	J18	K20	K22

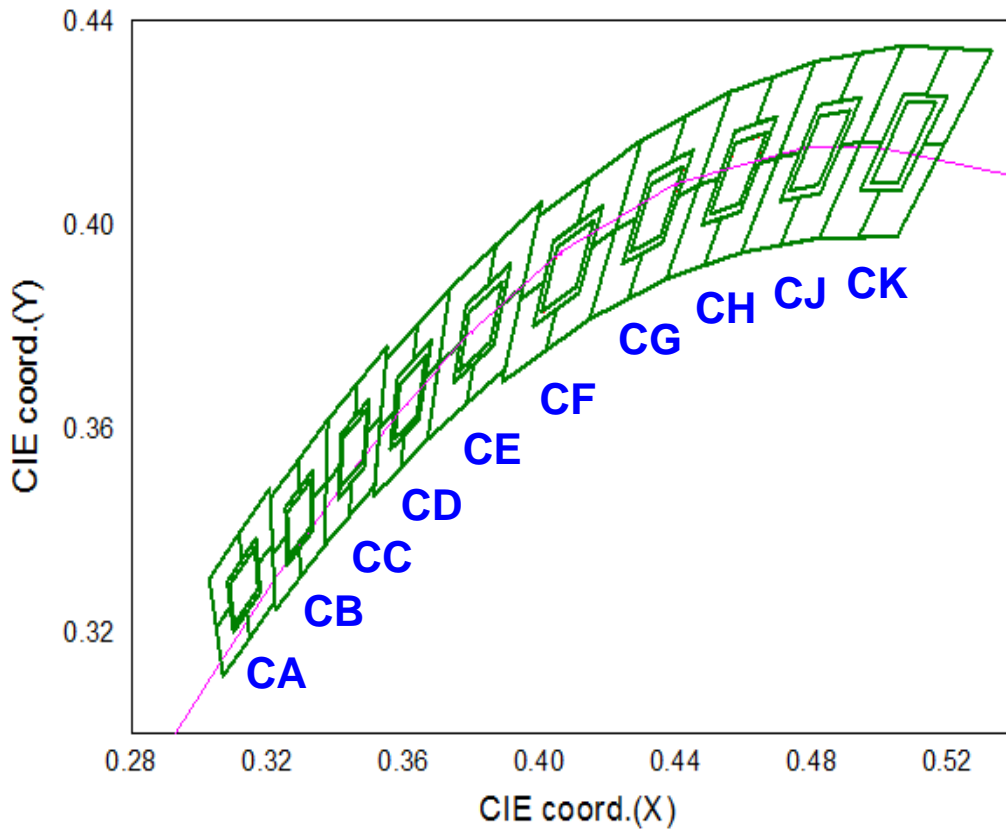
***Notes :**

(1) Calculated performance values are for reference only.

- All measurements were made under the standardized environment of Seoul Semiconductor.
In order to ensure availability, single color rank will not be orderable.

Color Bin Structure

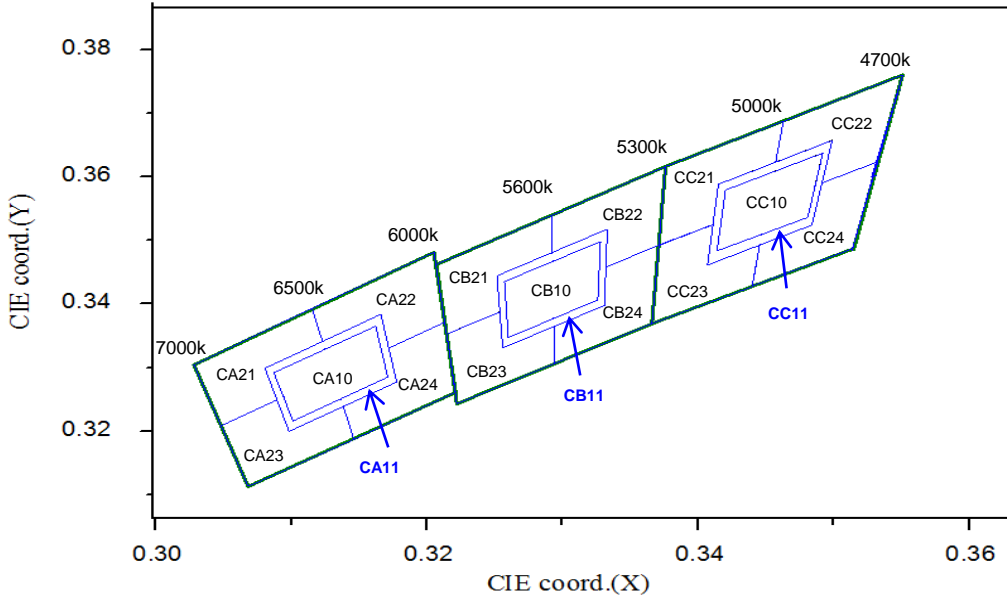
CIE Chromaticity Diagram $T_j=25^{\circ}\text{C}$, $I_f=150\text{mA}$



***Notes :**

- Energy Star binning applied to all 2600~7000K.
- Measurement Uncertainty of the Color Coordinates : ± 0.005

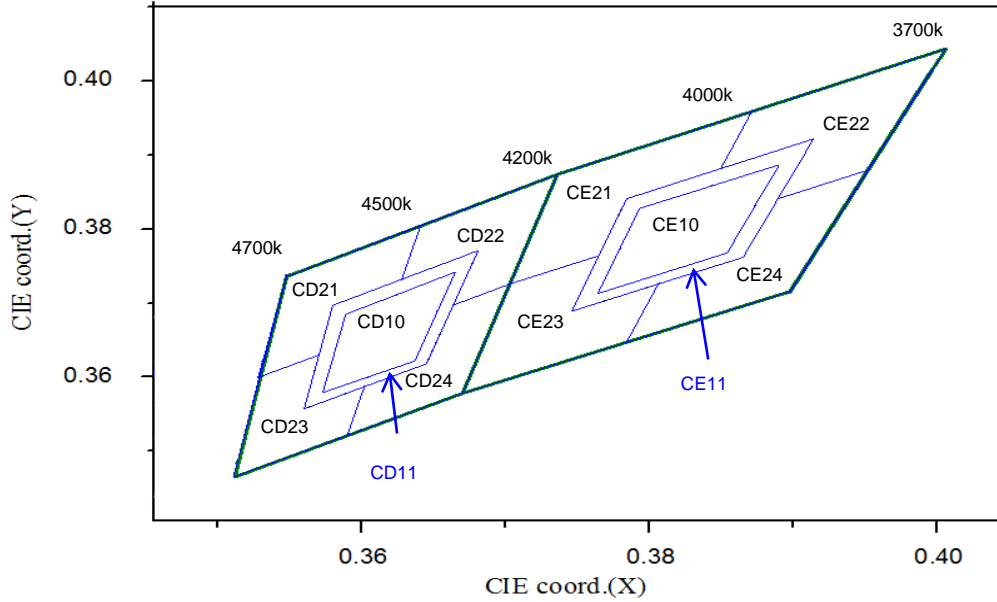
Color Bin Structure

CIE Chromaticity Diagram $T_j=25^\circ\text{C}$, $I_f=150\text{mA}$


CA10		CA11		CA21		CA22		CA23	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3087	0.3292	0.3080	0.3299	0.3028	0.3304	0.3115	0.3393	0.3048	0.3209
0.3162	0.3365	0.3166	0.3384	0.3115	0.3393	0.3205	0.3481	0.3131	0.3290
0.3171	0.3285	0.3178	0.3277	0.3131	0.3290	0.3213	0.3371	0.3146	0.3187
0.3101	0.3216	0.3098	0.3200	0.3048	0.3209	0.3131	0.3290	0.3068	0.3113
CA24		CB10		CB11		CB21		CB22	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3131	0.3290	0.3257	0.3435	0.3252	0.3444	0.3207	0.3462	0.3292	0.3539
0.3213	0.3371	0.3328	0.3498	0.3333	0.3518	0.3292	0.3539	0.3376	0.3616
0.3221	0.3261	0.3326	0.3406	0.3331	0.3398	0.3293	0.3423	0.3371	0.3493
0.3146	0.3187	0.3260	0.3347	0.3256	0.3331	0.3215	0.3353	0.3293	0.3423
CB23		CB24		CC10		CC11		CC21	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3215	0.3353	0.3293	0.3423	0.3420	0.3579	0.3415	0.3588	0.3376	0.3616
0.3293	0.3423	0.3371	0.3493	0.3492	0.3637	0.3499	0.3657	0.3463	0.3687
0.3294	0.3306	0.3366	0.3369	0.3481	0.3536	0.3484	0.3524	0.3452	0.3557
0.3222	0.3243	0.3294	0.3306	0.3414	0.3483	0.3407	0.3461	0.3371	0.3493
CC22		CC23		CC24					
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y				
0.3463	0.3687	0.3371	0.3492	0.3451	0.3557				
0.3551	0.3760	0.3451	0.3557	0.3532	0.3623				
0.3532	0.3623	0.3440	0.3427	0.3514	0.3487				
0.3451	0.3557	0.3366	0.3369	0.3440	0.3428				

Color Bin Structure

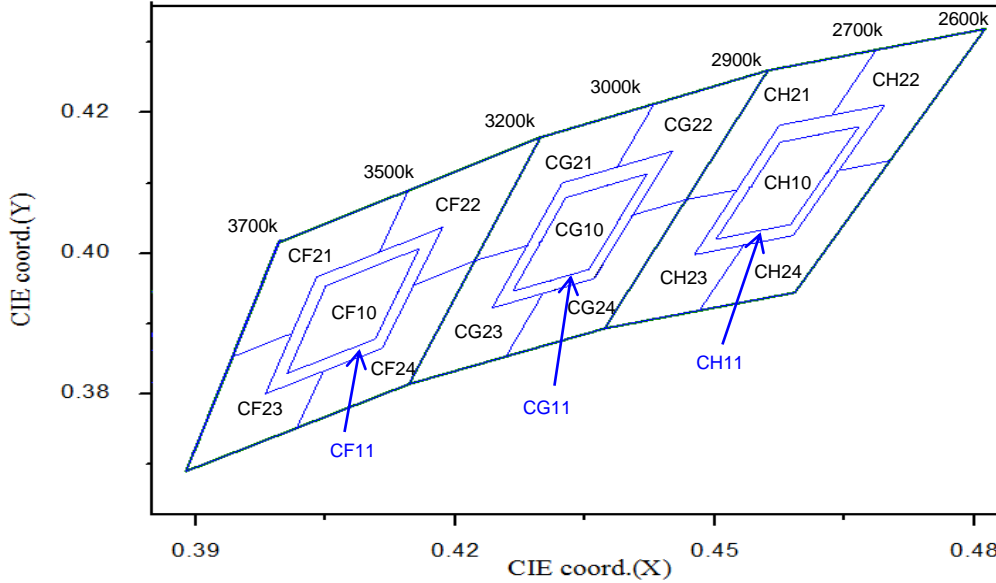
CIE Chromaticity Diagram $T_j=25^\circ\text{C}$, $I_f=150\text{mA}$



CD10		CD11		CD21		CD22		CD23	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3589	0.3685	0.3560	0.3557	0.3528	0.3599	0.3641	0.3805	0.3530	0.3601
0.3665	0.3742	0.3580	0.3697	0.3548	0.3736	0.3736	0.3874	0.3616	0.3663
0.3637	0.3622	0.3681	0.3771	0.3641	0.3805	0.3703	0.3726	0.3590	0.3521
0.3573	0.3579	0.3645	0.3618	0.3616	0.3663	0.3616	0.3663	0.3511	0.3465
CD24		CE10		CE11		CE21		CE22	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3616	0.3663	0.3764	0.3713	0.3746	0.3689	0.3703	0.3726	0.3828	0.3803
0.3703	0.3726	0.3793	0.3828	0.3784	0.3841	0.3736	0.3874	0.3871	0.3959
0.3670	0.3578	0.3890	0.3887	0.3914	0.3922	0.3871	0.3959	0.4006	0.4044
0.3590	0.3521	0.3854	0.3768	0.3865	0.3762	0.3828	0.3803	0.3952	0.3880
CE23		CE24							
CIE X	CIE Y	CIE X	CIE Y						
0.3670	0.3578	0.3784	0.3647						
0.3703	0.3726	0.3828	0.3803						
0.3828	0.3803	0.3952	0.3880						
0.3784	0.3647	0.3898	0.3716						

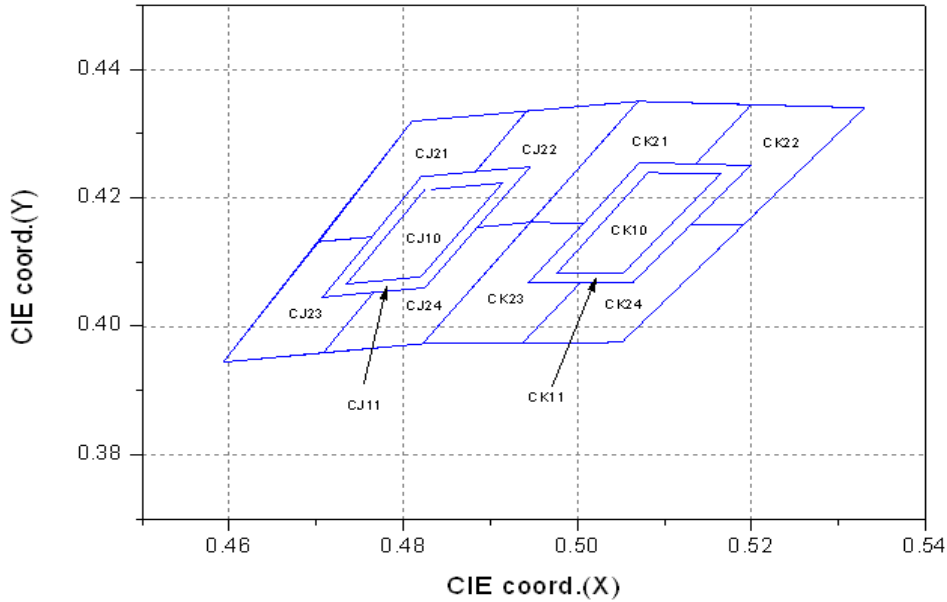
Color Bin Structure

CIE Chromaticity Diagram $T_j=25^{\circ}\text{C}$, $I_f=150\text{mA}$



CF10		CF11		CF21		CF22		CF23	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4006	0.3829	0.3981	0.3800	0.3996	0.4015	0.4146	0.4089	0.3943	0.3853
0.4051	0.3954	0.4040	0.3966	0.4146	0.4089	0.4299	0.4165	0.4082	0.3920
0.4159	0.4007	0.4186	0.4037	0.4082	0.3920	0.4223	0.3990	0.4017	0.3751
0.4108	0.3878	0.4116	0.3865	0.3943	0.3853	0.4082	0.3920	0.3889	0.3690
CF24		CG10		CG11		CG21		CG22	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4082	0.3920	0.4267	0.3946	0.4243	0.3922	0.4299	0.4165	0.4430	0.4212
0.4223	0.3990	0.4328	0.4079	0.4324	0.4100	0.4430	0.4212	0.4562	0.4260
0.4147	0.3814	0.4422	0.4113	0.4451	0.4145	0.4345	0.4033	0.4468	0.4077
0.4017	0.3751	0.4355	0.3977	0.4361	0.3964	0.4223	0.3990	0.4345	0.4033
CG23		CG24		CH10		CH11		CH21	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4223	0.3990	0.4345	0.4033	0.4502	0.4020	0.4477	0.3998	0.4562	0.4260
0.4345	0.4033	0.4468	0.4077	0.4576	0.4158	0.4575	0.4182	0.4687	0.4289
0.4259	0.3853	0.4373	0.3893	0.4667	0.4180	0.4697	0.4211	0.4585	0.4104
0.4147	0.3814	0.4259	0.3853	0.4588	0.4041	0.4591	0.4025	0.4468	0.4077
CH22		CH23		CH24					
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y				
0.4687	0.4289	0.4468	0.4077	0.4585	0.4104				
0.4813	0.4319	0.4585	0.4104	0.4703	0.4132				
0.4703	0.4132	0.4483	0.3919	0.4593	0.3944				
0.4585	0.4104	0.4373	0.3893	0.4483	0.3919				

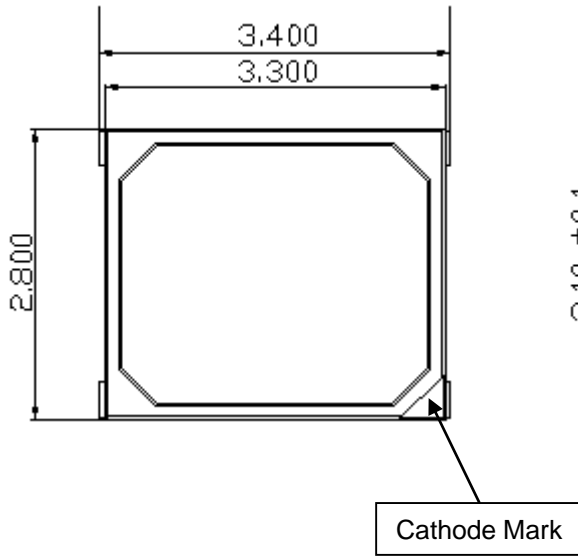
Color Bin Structure

CIE Chromaticity Diagram $T_f=25^\circ\text{C}$, $I_f=150\text{mA}$


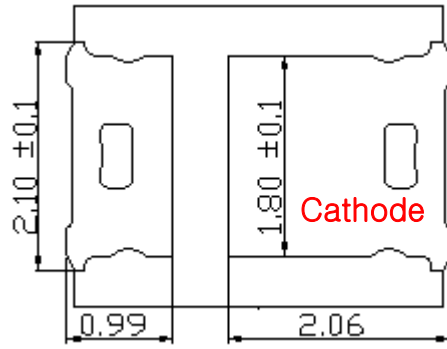
CJ10		CJ11		CJ21		CJ22		CJ23	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4825	0.4213	0.4821	0.4233	0.4810	0.4319	0.4942	0.4335	0.4703	0.4132
0.4735	0.4066	0.4707	0.4045	0.4703	0.4132	0.4824	0.4147	0.4593	0.3944
0.4820	0.4077	0.4825	0.4060	0.4824	0.4147	0.4946	0.4162	0.4708	0.3959
0.4914	0.4223	0.4946	0.4248	0.4942	0.4335	0.5070	0.4350	0.4824	0.4147
CJ24		CK10		CK11		CK21		CK22	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4824	0.4147	0.5081	0.4239	0.5071	0.4254	0.5070	0.4350	0.5200	0.4345
0.4708	0.3959	0.4976	0.4082	0.4943	0.4067	0.4946	0.4162	0.5066	0.4160
0.4822	0.3973	0.5052	0.4082	0.5043	0.4067	0.5066	0.4160	0.5191	0.4158
0.4946	0.4162	0.5165	0.4238	0.5199	0.4250	0.5200	0.4345	0.5330	0.4340
CK23		CK24							
CIE X	CIE Y	CIE X	CIE Y						
0.4946	0.4162	0.5066	0.4160						
0.4822	0.3973	0.4937	0.3974						
0.4937	0.3974	0.5051	0.3975						
0.5066	0.4160	0.5191	0.4158						

Mechanical Dimensions

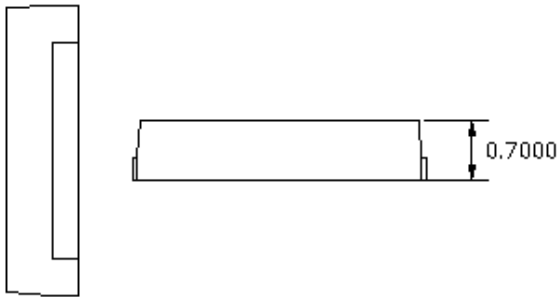
Top View



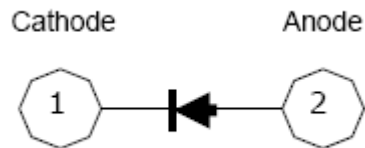
Bottom View



Side View



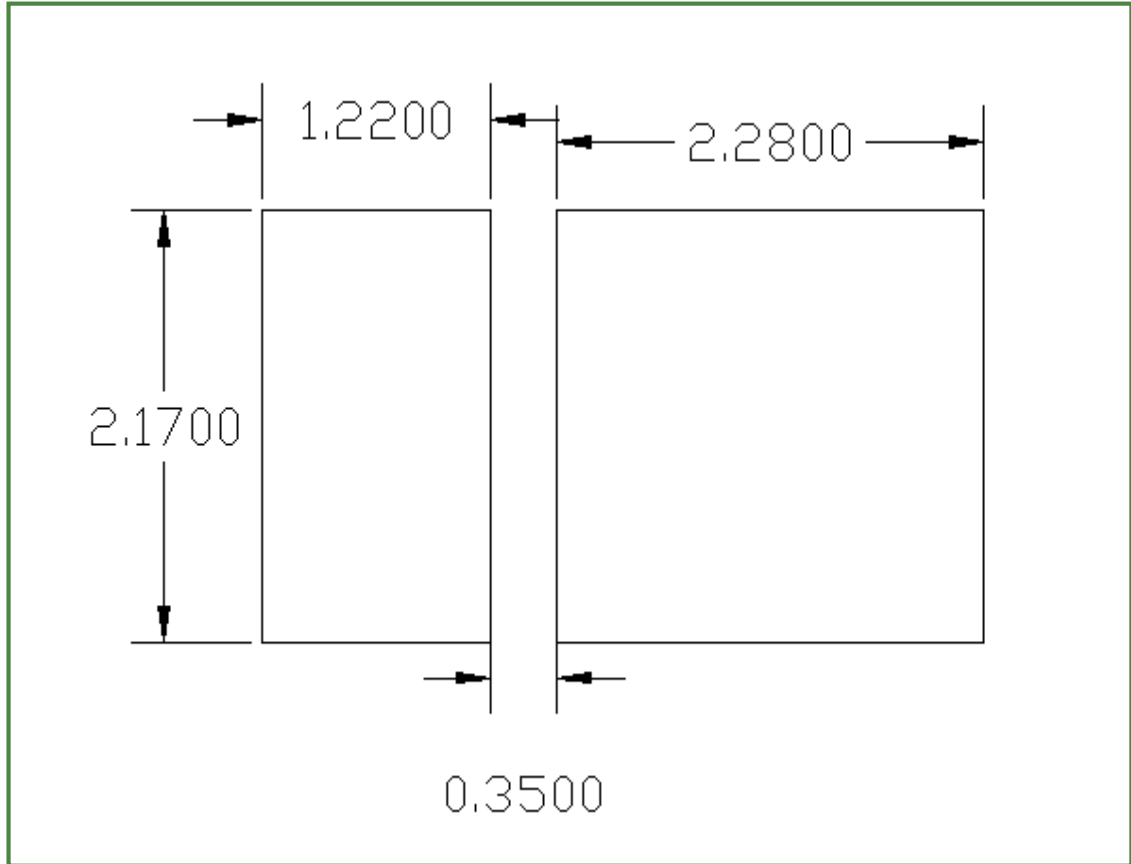
Circuit



Notes :

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is $\pm 0.2\text{mm}$

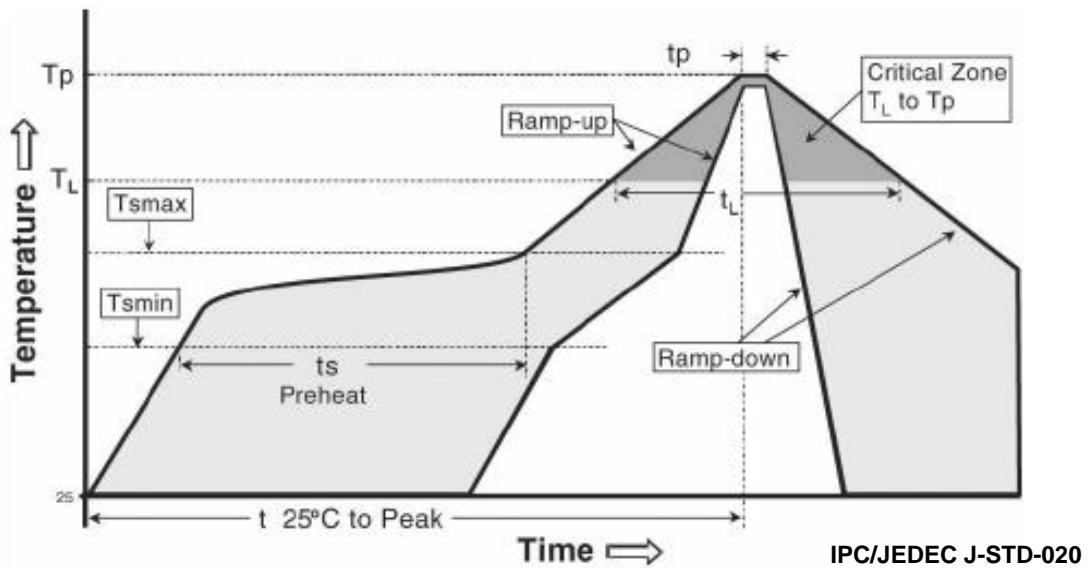
Recommended Solder Pad



Notes :

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) This drawing without tolerances are for reference only
- (4) Undefined tolerance is $\pm 0.1\text{mm}$
- (5) The appearance and specifications of the product may be changed for improvement without notice.

Reflow Soldering Characteristics

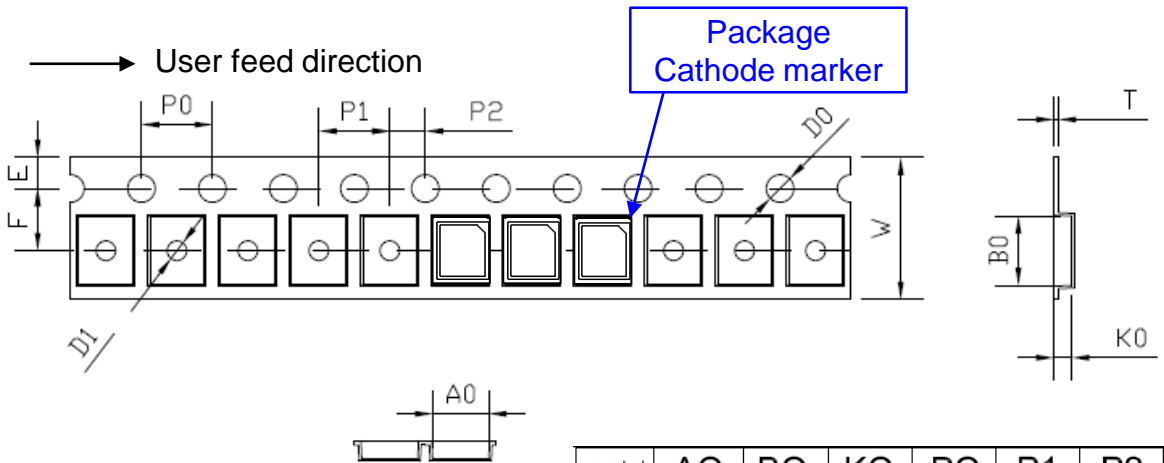


Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_{s_max} to T_p)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (T_{s_min}) - Temperature Max (T_{s_max}) - Time (T_{s_min} to T_{s_max}) (t_s)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (T_L) - Time (t_L)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T_p)	215°C	260°C
Time within 5°C of actual Peak Temperature (t_p) ²	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

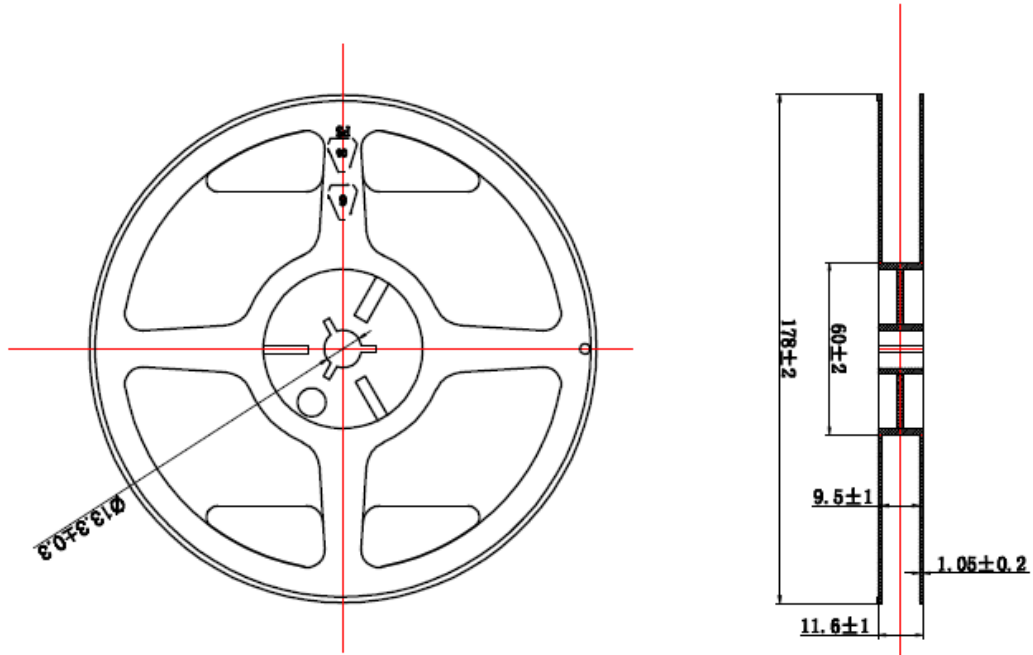
Caution :

- (1) Reflow soldering is recommended not to be done more than two times
In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered
When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

Emitter Tape & Reel Packaging



symbol	AO	BO	KO	PO	P1	P2
Spec	3.0±0.10	3.75±0.15	1.05±0.15	4.0±0.10	4.0±0.10	2.0±0.10
symbol	W	T	E	F	DO	D1
Spec	8.00±0.10	0.20±0.05	1.75±0.10	3.5±0.10	1.5±0.05	1.10±0.10

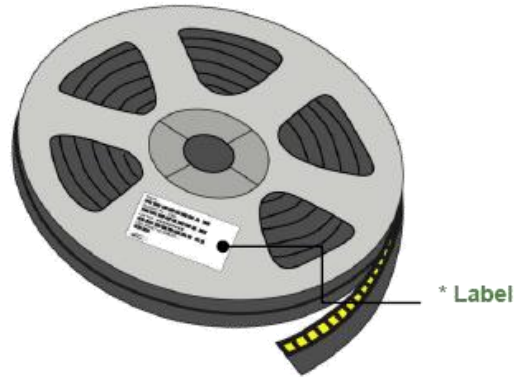


Notes :

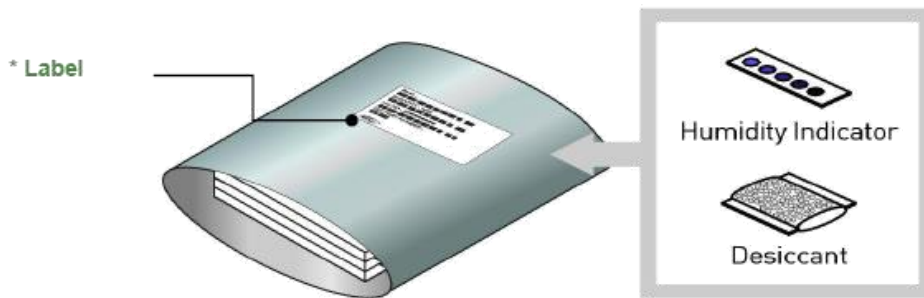
- (1) Quantity : Max 4,000pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2\text{mm}$
- (3) Adhesion Strength of Cover Tape
Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape.
- (4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.

Emitter Tape & Reel Packaging

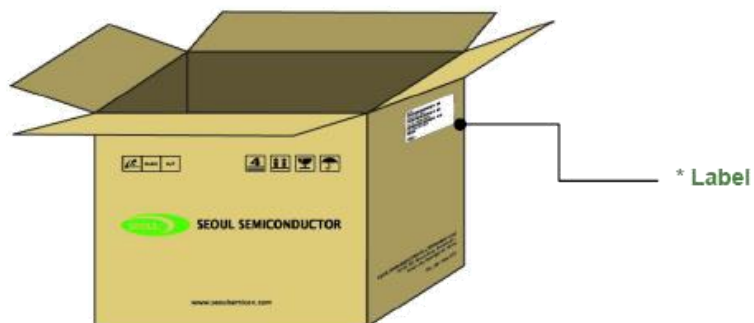
Reel



Aluminum Bag



Outer Box



Product Nomenclature

Table 7. Part Numbering System : X₁X₂X₃X₄X₅X₆X₇X₈

Part Number Code	Description	Part Number	Value
X ₁	Company	S	
X ₂	Top View LED series	T	
X ₃	Color Specification	W8	CRI 80
X ₄	Package series	A	A series
X ₅ X ₆	Characteristic code	12	
X ₇	Version	D	

Table 8. Lot Numbering System : Y₁Y₂Y₃Y₄Y₅Y₆Y₇Y₈Y₉Y₁₀–Y₁₁Y₁₂Y₁₃Y₁₄Y₁₅Y₁₆Y₁₇

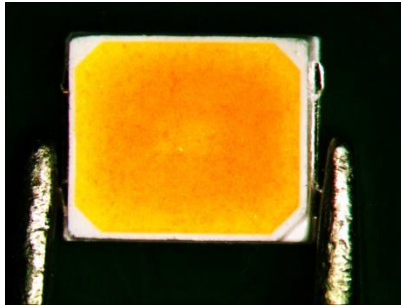
Lot Number Code	Description	Lot Number	Value
Y ₁ Y ₂	Year		
Y ₃	Month		
Y ₄ Y ₅	Day		
Y ₆	Top View LED series		
Y ₇ Y ₈ Y ₉ Y ₁₀	Mass order		
Y ₁₁ Y ₁₂ Y ₁₃ Y ₁₄ Y ₁₅ Y ₁₆ Y ₁₇	Internal Number		

Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.

Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant.

The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMT techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

a. Recommend conditions after opening the package

- Sealing

- Temperature : 5 ~ 30°C Humidity : less than RH60%

b. If the package has been opened more than 4 week(MSL_2a) or the color of the desiccant changes, components should be dried for 10-24hr at 65±5°C

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication.

These products are dangerous if they are burned or shredded in the process of disposal.

It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.

When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

Precaution for Use

- (10) The appearance and specifications of the product may be modified for improvement without notice.
- (11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.
- (12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (13) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (14) The driving circuit must be designed to allow forward voltage only when it is ON or OFF.
If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (15) Similar to most Solid state devices;
LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS).
Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
(shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufactures and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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